

Large Rashba splitting, carriers mobility and Valley polarization in 1T-SnS₂/MoTe₂ heterostructure

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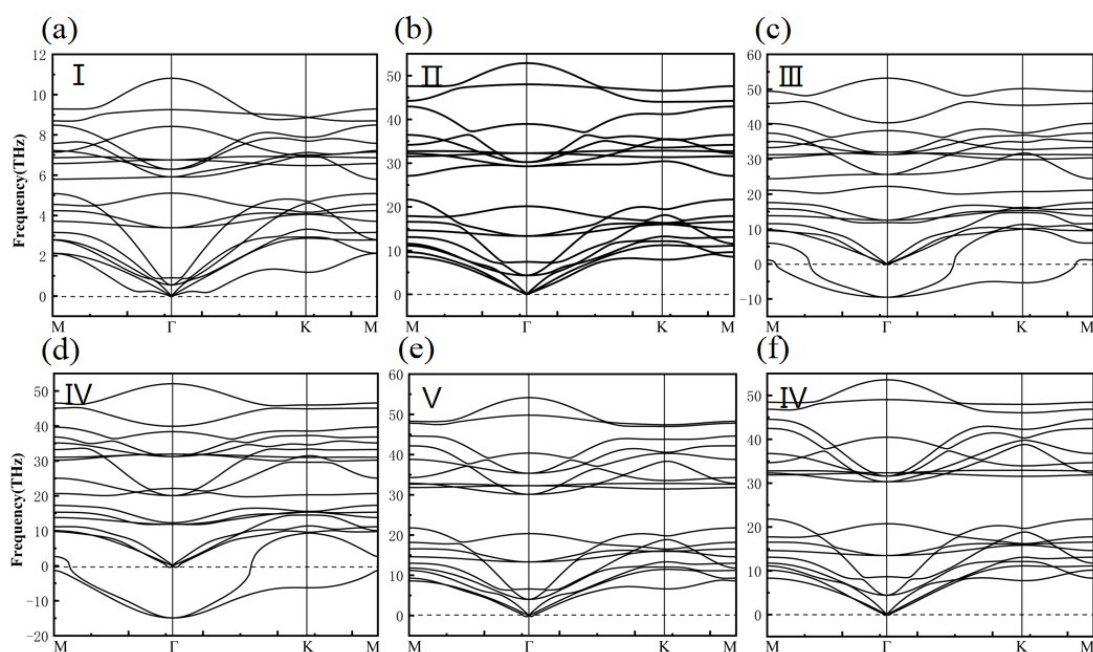


Fig S1. (a)-(f) Calculated phonon spectra for the six possible stacking configurations.

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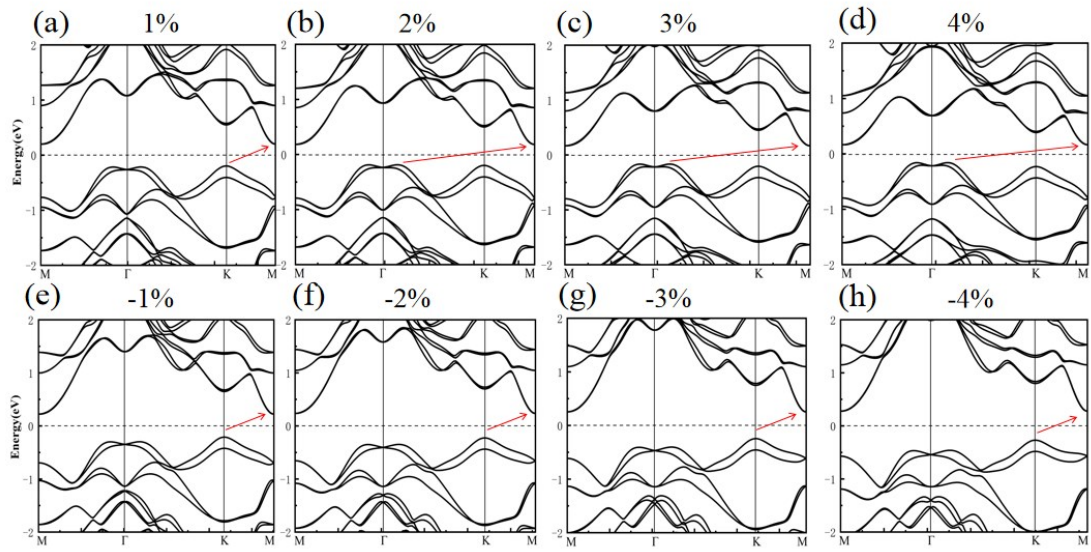


Fig S2. (a)-(h) Band structures of the 1T-SnS₂/MoTe₂ heterostructure with biaxial strain.